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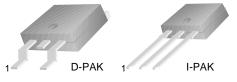
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### **KSH210**

### **D-PAK for Surface Mount Applications**

- High DC Current Gain
- Low Collector Emitter Saturation Voltage
- Lead Formed for Surface Mount Applications (No Suffix)
- Straight Lead (I-PAK, " I " Suffix)



1.Base 2.Collector 3.Emitter

### **PNP Epitaxial Silicon Transistor**

### Absolute Maximum Ratings T<sub>C</sub>=25°C unless otherwise noted

| Symbol           | Parameter                                     | Value      | Units |
|------------------|---|------------|-------|
| V <sub>CBO</sub> | Collector-Base Voltage                        | - 40       | V     |
| V <sub>CEO</sub> | Collector-Emitter Voltage                     | - 25       | V     |
| V <sub>EBO</sub> | Emitter-Base Voltage                          | - 8        | V     |
| I <sub>C</sub>   | Collector Current (DC)                        | - 5        | А     |
| I <sub>CP</sub>  | Collector Peck Current (Pulse)                | - 10       | А     |
| I <sub>B</sub>   | Base Current                                  | - 1        | А     |
| P <sub>C</sub>   | Collector Dissipation (T <sub>C</sub> = 25°C) | 12.5       | W     |
|                  | Collector Dissipation (T <sub>a</sub> = 25°C) | 1.4        | W     |
| T <sub>J</sub>   | Junction Temperature                          | 150        | °C    |
| T <sub>STG</sub> | Storage Temperature                           | - 65 ~ 150 | °C    |

### **Electrical Characteristics** $T_C=25$ °C unless otherwise noted

| Symbol                 | Parameter                              | Test Condition                                    | Min. | Max.  | Units |
|------------------------|--|---|------|-------|-------|
| V <sub>CEO</sub> (sus) | * Collector-Emitter Sustaining Voltage | $I_C = -10 \text{mA}, I_B = 0$                    | -25  |       | V     |
| I <sub>CBO</sub>       | Collector Cut-off Current              | $V_{CB} = -40V, I_{E} = 0$                        |      | -100  | nA    |
| I <sub>EBO</sub>       | Emitter Cut-off Current                | $V_{EBO} = -8V, I_{C} = 0$                        |      | -100  | nA    |
| h <sub>FE</sub>        | * DC Current Gain                      | V <sub>CE</sub> = - 1V, I <sub>C</sub> = - 500mA  | 70   |       |       |
|                        |  | $V_{CE} = -1V, I_{C} = -2A$                       | 45   | 180   |       |
|                        |  | $V_{CE} = -2V, I_{C} = -5A$                       | 10   |       |       |
| V <sub>CE</sub> (sat)  | * Collector-Emitter Saturation Voltage | I <sub>C</sub> = - 500mA, I <sub>B</sub> = - 50mA |      | -0.3  | V     |
|                        |  | $I_C = -2A$ , $I_B = -200mA$                      |      | -0.75 | V     |
|                        |  | $I_C = -5A, I_B = -1A$                            |      | -1.8  | V     |
| V <sub>BE</sub> (sat)  | * Base-Emitter Saturation Voltage      | I <sub>C</sub> = - 5A, I <sub>B</sub> = - 1A      |      | -2.5  | V     |
| V <sub>BE</sub> (on)   | * Base-Emitter On Voltage              | V <sub>CE</sub> = - 1V, I <sub>C</sub> = - 2A     |      | -1.6  | V     |
| f <sub>T</sub>         | Current Gain Bandwidth Product         | V <sub>CE</sub> = - 10V, I <sub>C</sub> = - 100mA | 65   |       | MHz   |
| C <sub>ob</sub>        | Output Capacitance                     | $V_{CB} = -10V, I_{E} = 0, f = 0.1MHz$            |      | 120   | pF    |

<sup>\*</sup> Pulse Test: PW≤300μs, Duty Cycle≤2%

# **Typical Characteristics**

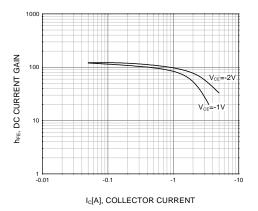


Figure 1. DC current Gain

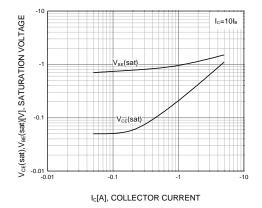


Figure 2. Base-Emitter Saturation Voltage Collector-Emitter Saturation Voltage

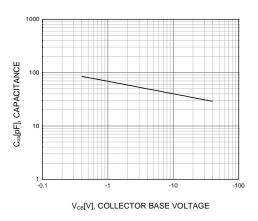


Figure 3. Collector Output Capacitance

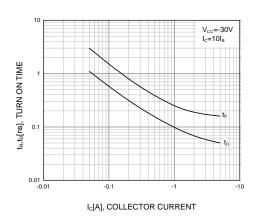


Figure 4. Turn On Time

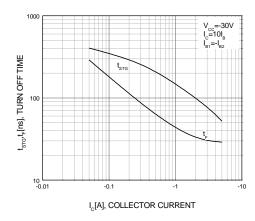


Figure 5. Turn Off Time

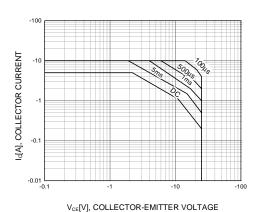


Figure 6. Safe Operating Area

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# Typical Characteristics (Continued)

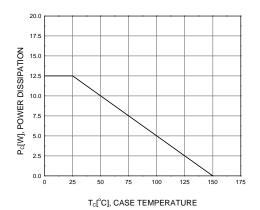
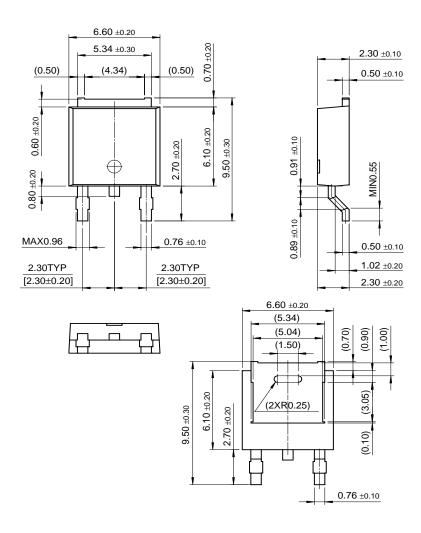


Figure 7. Power Derating

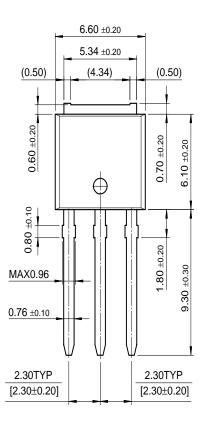
## **Package Dimensions**

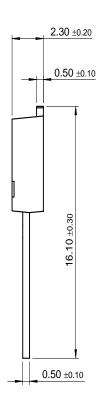
## D-PAK



# Package Dimensions (Continued)

## I-PAK







Dimensions in Millimeters

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| CoolFET™                             | FASTr™              | MicroFET™              | PowerTrench <sup>®</sup> | SuperSOT™-6           |
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